# Characterisation of the new Hamamatsu MPPC25 SiPMs

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- Noise measurement for the new MPPC25
- Comparison with older MPPC revision
- Noise vs bias voltage correlation
- Signal vs bias voltage correlation
- Uniformity scans for the new Hamburg tiles
- Noise measurement for the Ketek SiPM

#### Noise measurements

#### SiPM $\rightarrow$ Ist preamp (~x9) $\rightarrow$ 2nd preamp (~x5) $\rightarrow$ counter

- Scan over several SiPM bias voltages
- simple threshold scan in 5 mV steps on the counter
- I s integration time for each bias voltage and counter threshold

#### Signal measurements

🛃 source → scinti tile + SiPM → preamp → picoscope

- 9.6ns integration window to avoid recording afterpulses
- 3.5 kHz Sr90  $e^{-}$  source (conversion factor to MIP = 0.8)
- Triggered on a 2nd scintillator, below the tile under investigation

# New MPPC25 - Noise rate @ reference VBias



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# Light yield with several Tiles

Results of 9-point scans with 90-Sr source

(1 cm<sup>2</sup> with evenly placed points in the middle of the tile.)

#### new MPPC25

#### old MPPC25

Tile	E (MPV) [p.e.]	E (mean) [p.e.]	uniformity [p.e.]	E (MPV) [p.e.]	E (mean) [p.e.]	uniformity [p.e.]
T3B	13	14.3	1.1	7.5	8.3	1.1
ITEP	8	9.2	3.0	4.5	5.6	1.6
нн	15	16.4	1.0	8.5	9.5	0.7

The relative yield between tiles should be correct BUT, after investigating the new MPPC25 active area, we found a big dust spot that must have affected the absolute yield. The next measurements have been taken after thorough cleaning.

# New MPPC25 - Noise rate vs VBias

Noise level vs bias voltage



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# New MPPC25 - Mean Signal vs VBias



# New MPPC25 - Signal distribution vs VBias



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# Signal to noise ratio

Signal strength vs VBias



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# Uniformity scan - I hole



# Uniformity scan - 2 holes



## Ketek - Noise rate vs VBias



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# Ketek - Noise rate @ 35 V



# Conclusions

- New MPPC25 seem to have higher noise than the previous revision
- BUT higher light yield for signal
- Ketek handle noise very well over a broader overbias voltage range
- Uniformity scans show that the quality (holes, air bubbles) of the reflective foil does not affect the uniformity
- We still need to investigate the gain vs temperature dependence (need to replace our climate chamber)

# Backup - Signal to noise ratio

Vbias	Mean	mpv (mips)	#p.e. for noise < 100Hz	signal/noise	mip cut
66,28	14	10,08	4	2,52	0,40
66,40	15	10,80	4	2,70	0,37
66,60	17	12,24	5	2,45	0,41
67,05	21	15,12	6	2,52	0,40
67,28	24	17,28	6	2,88	0,35
67,40	25	18,00	7	2,57	0,39
67,60	27	19,44	7	2,78	0,36
67,80	30	21,60	8	2,70	0,37
68,00	31,5	22,68	9	2,52	0,40

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2,63

0,14

## **Backup - Noise profiles for different VBias**



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